

60V Dual P-Channel Enhancement Mode MOSFET

-13.6 A

Voltage

Current

Features

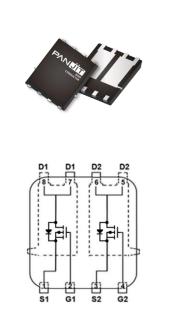
• R_{DS(ON)}, V_{GS}@-10V, I_D@-7.5A<68mΩ

-60 V

- Rds(on), Vgs@-4.5V, Id@-4A<85m Ω
- Low Gate Charge
- High switching speed
- Improved dv/dt capability
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060B-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.092 grams



Maximum Ratings and Thermal Characteristics (T_A=25^oC unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	-60	V	
Gate-Source Voltage		V _{GS}	±20	v	
Continuous Drain Current ^(Note 4)	Tc=25°C		-13.6		
	Tc=100°C		-8.6	A	
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	-55		
Power Dissipation	T _C =25°C	D	23	14/	
	Tc=100°C	Po	9	W	
Continuous Drain Current ^(Note 4)	T _A =25°C	١ _D	-3.7	•	
	T _A =70°C		-3.0	A	
Power Dissipation	T _A =25°C	D	1.7	- W	
	T _A =70°C	PD	1.1		
Single Pulse Avalanche Energy ^(Note 6)		Eas	30	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R _{θJC}	5.5	- ∘C/W	
	Junction to Ambient	RθJA	73.5		



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	ss V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.6	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-7.5A	-	57	68	mΩ
		V _{GS} =-4.5V, I _D =-4A	-	75	85	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
Dynamic ^(Note 7)						
Total Gate Charge	Qg	V _{DS} =-30V, I _D =-7.5A, V _{GS} =-10V ^(Note 2,3)	-	17	-	nC
Gate-Source Charge	Qgs		-	2.8	-	
Gate-Drain Charge	Q_{gd}		-	3.6	-	
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V, f=1MHZ	-	879	-	pF
Output Capacitance	Coss		-	70	-	
Reverse Transfer Capacitance	Crss		-	47	-	
Turn-On Delay Time	td _(on)	V _{DS} =-30V, I _D =-1A, V _{GS} =-10V, R _G =6Ω (Note 2,3)	-	8.4	-	ns
Turn-On Rise Time	tr		-	30	-	
Turn-Off Delay Time	td _(off)		-	52	-	
Turn-Off Fall Time	t _f		-	16	-	
Drain-Source Diode						
Diode Forward Current	ls	Tc=25°C	-	-	-13.6	А
Diode Forward Voltage	Vsd	Is=-1A, V _{GS} =0V	-	-0.73	-1	V

NOTES :

1. Pulse width <300us, Duty cycle <2%.

2. Essentially independent of operating temperature typical characteristics.

3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial $T_J = 25$ °C.

4. The maximum current rating is package limited.

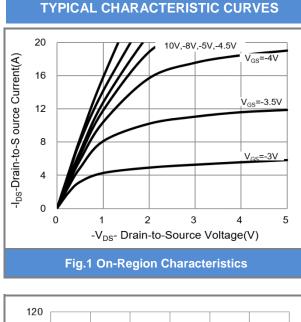
5. R JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.

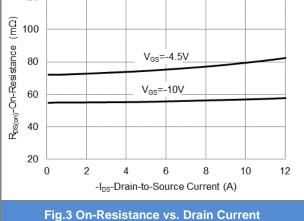
6. The test condition is L=0.1mH, I_{AS} = -25A, V_{DD} = -25V, V_{GS} = -10V, Starting T_J=25°C. Guaranteed by design, not subject to production testing.

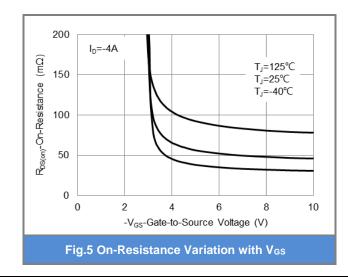
SEMI CONDUCTOR

PANJ

PJQ5863A-AU







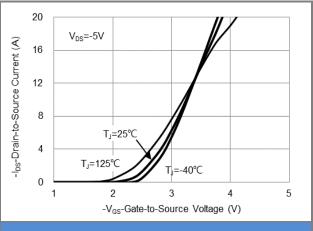


Fig.2 Transfer Characteristics

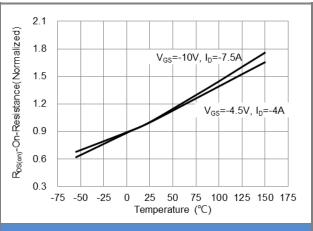
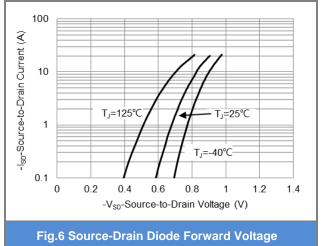


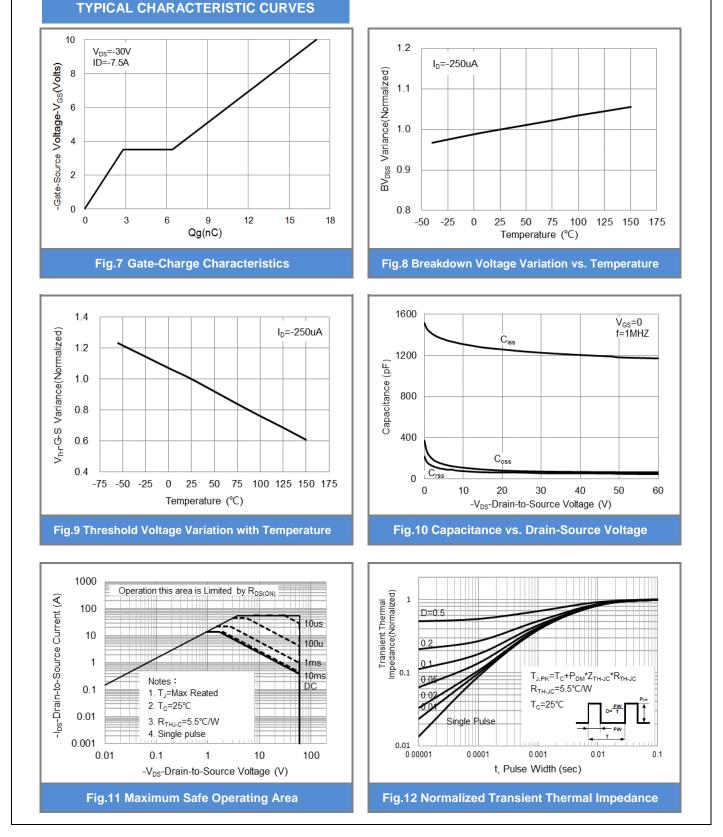
Fig.4 On-Resistance vs. Junction temperature



November 8,2022

PJQ5863A-AU-REV.00





SEM CONDUCTOR

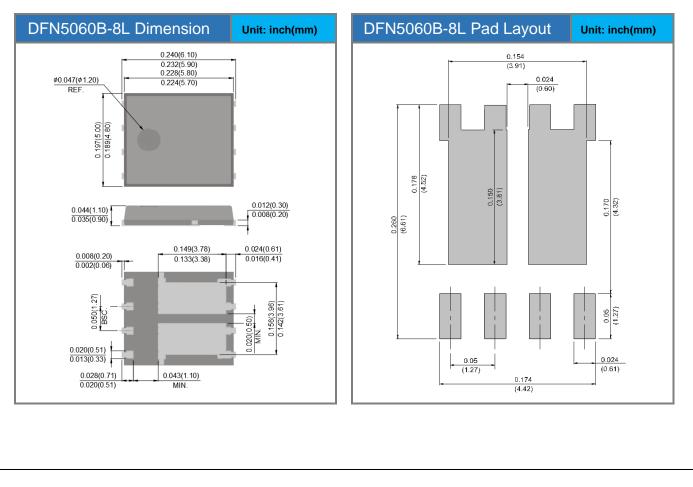
PJQ5863A-AU



Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5863A-AU_R2_002A1	DFN5060B-8L	3K pcs / 13" reel	Q5863A	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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